

# LM13700 Dual Operational Transconductance Amplifiers with Linearizing Diodes and Buffers

Check for Samples: [LM13700](#)

## FEATURES

- $g_m$  adjustable over 6 decades
- Excellent  $g_m$  linearity
- Excellent matching between amplifiers
- Linearizing diodes
- High impedance buffers
- High output signal-to-noise ratio

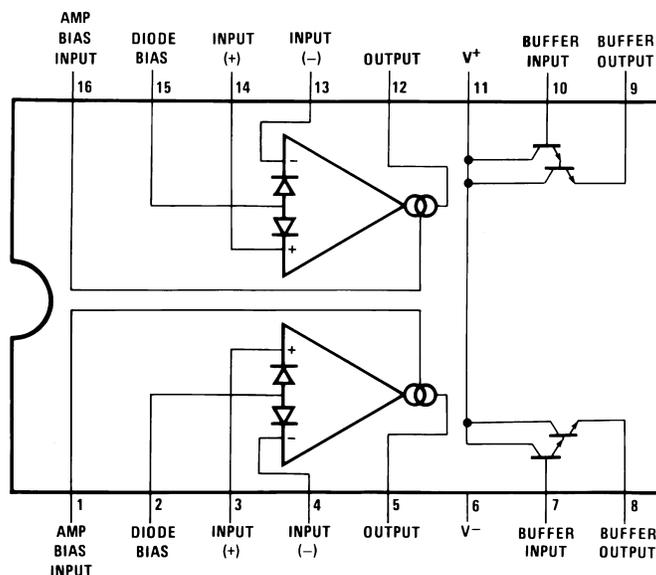
## APPLICATIONS

- Current-controlled amplifiers
- Current-controlled impedances
- Current-controlled filters
- Current-controlled oscillators
- Multiplexers
- Timers
- Sample-and-hold circuits

## DESCRIPTION

The LM13700 series consists of two current controlled transconductance amplifiers, each with differential inputs and a push-pull output. The two amplifiers share common supplies but otherwise operate independently. Linearizing diodes are provided at the inputs to reduce distortion and allow higher input levels. The result is a 10 dB signal-to-noise improvement referenced to 0.5 percent THD. High impedance buffers are provided which are especially designed to complement the dynamic range of the amplifiers. The output buffers of the LM13700 differ from those of the LM13600 in that their input bias currents (and hence their output DC levels) are independent of  $I_{ABC}$ . This may result in performance superior to that of the LM13600 in audio applications.

## Connection Diagram



**Figure 1. Top View  
Dual-In-Line and Small Outline Packages**



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### Absolute Maximum Ratings <sup>(1)</sup>

Supply Voltage	
LM13700	36 V <sub>DC</sub> or ±18V
Power Dissipation <sup>(2)</sup> T <sub>A</sub> = 25°C	
LM13700N	570 mW
Differential Input Voltage	±5V
Diode Bias Current (I <sub>D</sub> )	2 mA
Amplifier Bias Current (I <sub>ABC</sub> )	2 mA
Output Short Circuit Duration	Continuous
Buffer Output Current <sup>(3)</sup>	20 mA
Operating Temperature Range	
LM13700N	0°C to +70°C
DC Input Voltage	+V <sub>S</sub> to -V <sub>S</sub>
Storage Temperature Range	-65°C to +150°C
Soldering Information	
Dual-In-Line Package	
Soldering (10 sec.)	260°C
Small Outline Package	
Vapor Phase (60 sec.)	215°C
Infrared (15 sec.)	220°C

- (1) "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits.
- (2) For operation at ambient temperatures above 25°C, the device must be derated based on a 150°C maximum junction temperature and a thermal resistance, junction to ambient, as follows: LM13700N, 90°C/W; LM13700M, 110°C/W.
- (3) Buffer output current should be limited so as to not exceed package dissipation.

**Electrical Characteristics <sup>(1)</sup>**

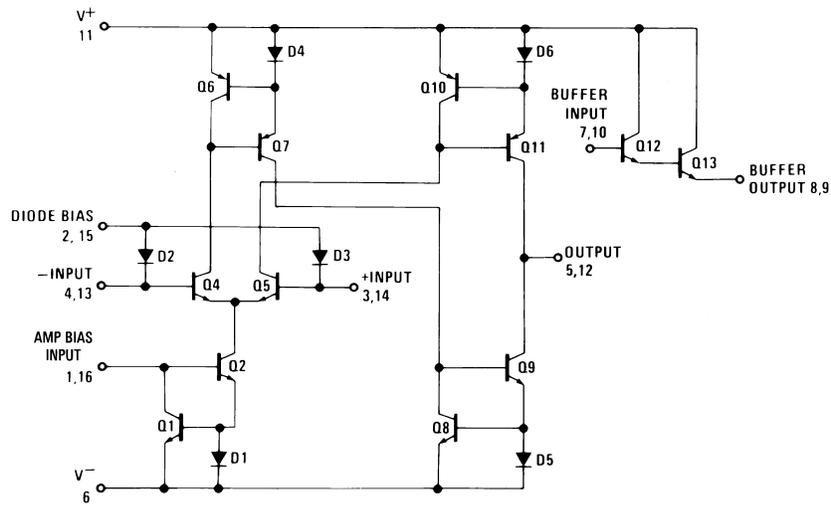
Parameter	Conditions	LM13700			Units
		Min	Typ	Max	
Input Offset Voltage ( $V_{OS}$ )	Over Specified Temperature Range		0.4	4	mV
	$I_{ABC} = 5 \mu A$		0.3	4	
$V_{OS}$ Including Diodes	Diode Bias Current ( $I_D$ ) = 500 $\mu A$		0.5	5	mV
Input Offset Change	$5 \mu A \leq I_{ABC} \leq 500 \mu A$		0.1	3	mV
Input Offset Current			0.1	0.6	$\mu A$
Input Bias Current	Over Specified Temperature Range		0.4	5	$\mu A$
			1	8	
Forward		6700	9600	13000	$\mu mho$
Transconductance ( $g_m$ )	Over Specified Temperature Range	5400			
$g_m$ Tracking			0.3		dB
Peak Output Current	$R_L = 0, I_{ABC} = 5 \mu A$		5		
	$R_L = 0, I_{ABC} = 500 \mu A$	350	500	650	$\mu A$
	$R_L = 0$ , Over Specified Temp Range	300			
Peak Output Voltage					
Positive	$R_L = \infty, 5 \mu A \leq I_{ABC} \leq 500 \mu A$	+12	+14.2		V
Negative	$R_L = \infty, 5 \mu A \leq I_{ABC} \leq 500 \mu A$	-12	-14.4		V
Supply Current	$I_{ABC} = 500 \mu A$ , Both Channels		2.6		mA
$V_{OS}$ Sensitivity					
Positive	$\Delta V_{OS}/\Delta V^+$		20	150	$\mu V/V$
Negative	$\Delta V_{OS}/\Delta V^-$		20	150	$\mu V/V$
CMRR		80	110		dB
Common Mode Range		$\pm 12$	$\pm 13.5$		V
Crosstalk	Referred to Input <sup>(2)</sup>		100		dB
	$20 \text{ Hz} < f < 20 \text{ kHz}$				
Differential Input Current	$I_{ABC} = 0$ , Input = $\pm 4V$		0.02	100	nA
Leakage Current	$I_{ABC} = 0$ (Refer to Test Circuit)		0.2	100	nA
Input Resistance		10	26		k $\Omega$
Open Loop Bandwidth			2		MHz
Slew Rate	Unity Gain Compensated		50		V/ $\mu s$
Buffer Input Current	<sup>(2)</sup>		0.5	2	$\mu A$
Peak Buffer Output Voltage	<sup>(2)</sup>	10			V

(1) These specifications apply for  $V_S = \pm 15V$ ,  $T_A = 25^\circ C$ , amplifier bias current ( $I_{ABC}$ ) = 500  $\mu A$ , pins 2 and 15 open unless otherwise specified. The inputs to the buffers are grounded and outputs are open.

(2) These specifications apply for  $V_S = \pm 15V$ ,  $I_{ABC} = 500 \mu A$ ,  $R_{OUT} = 5 \text{ k}\Omega$  connected from the buffer output to  $-V_S$  and the input of the buffer is connected to the transconductance amplifier output.

Schematic Diagram

Figure 2. One Operational Transconductance Amplifier



Typical Application

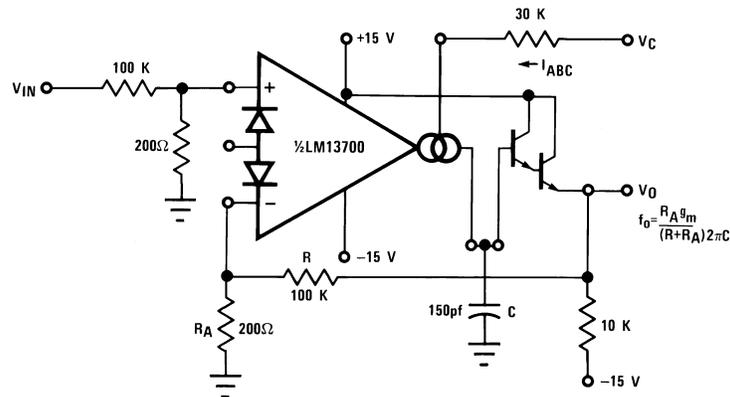
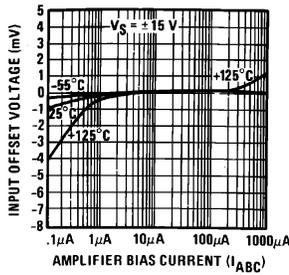


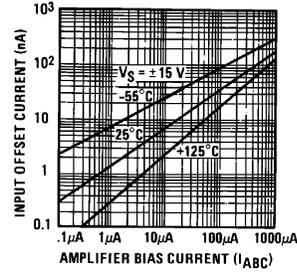
Figure 3. Voltage Controlled Low-Pass Filter

Typical Performance Characteristics

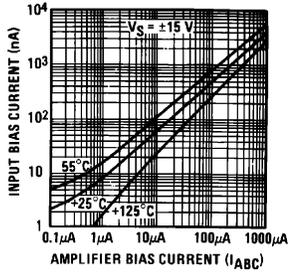
Input Offset Voltage



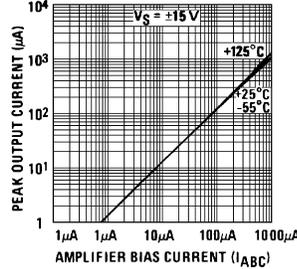
Input Offset Current



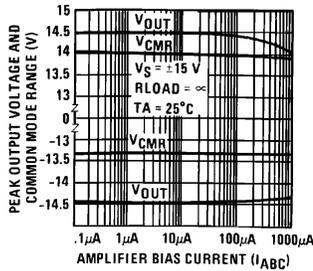
Input Bias Current



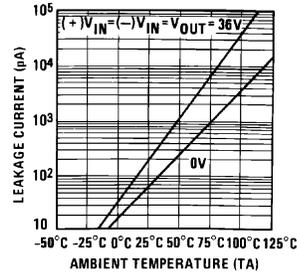
Peak Output Current



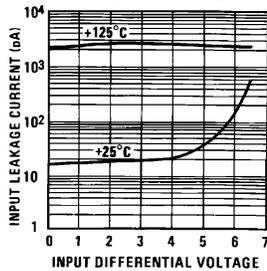
Peak Output Voltage and Common Mode Range



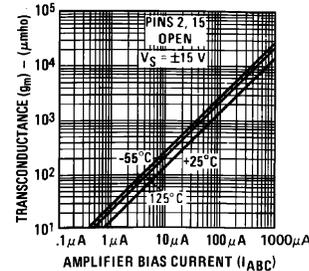
Leakage Current



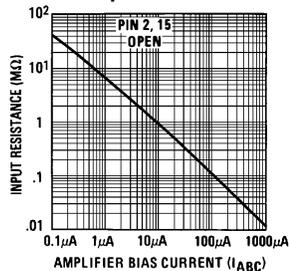
Input Leakage



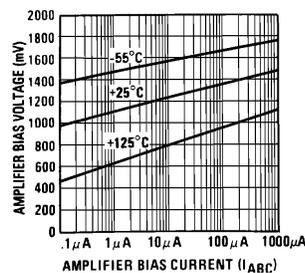
Transconductance



Input Resistance

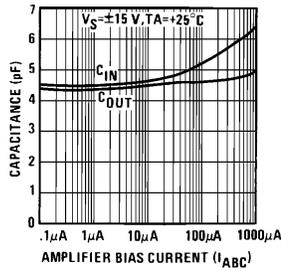


Amplifier Bias Voltage vs. Amplifier Bias Current

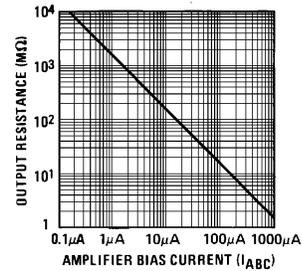


Typical Performance Characteristics (continued)

Input and Output Capacitance



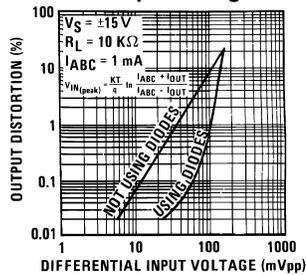
Output Resistance



Distortion

vs.

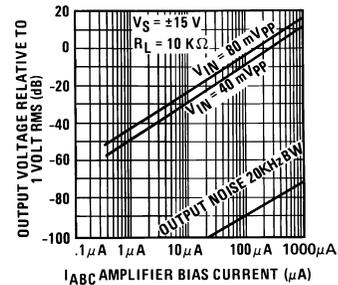
Differential Input Voltage



Voltage

vs.

Amplifier Bias Current



Output Noise

vs.

Frequency

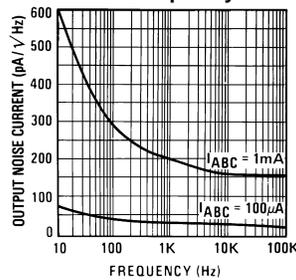
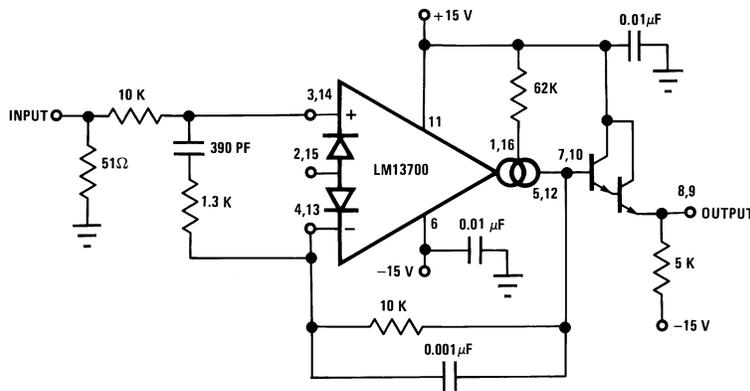


Figure 4. Unity Gain Follower



Typical Performance Characteristics (continued)

Figure 5. Leakage Current Test Circuit

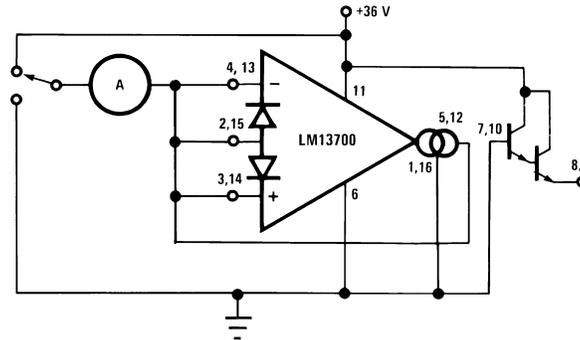
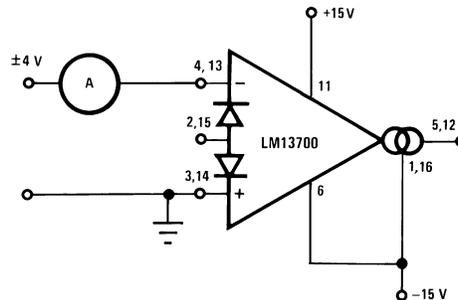


Figure 6. Differential Input Current Test Circuit



Circuit Description

The differential transistor pair  $Q_4$  and  $Q_5$  form a transconductance stage in that the ratio of their collector currents is defined by the differential input voltage according to the transfer function:

$$V_{IN} = \frac{kT}{q} \ln \frac{I_5}{I_4} \tag{1}$$

where  $V_{IN}$  is the differential input voltage,  $kT/q$  is approximately 26 mV at 25°C and  $I_5$  and  $I_4$  are the collector currents of transistors  $Q_5$  and  $Q_4$  respectively. With the exception of  $Q_{12}$  and  $Q_{13}$ , all transistors and diodes are identical in size. Transistors  $Q_1$  and  $Q_2$  with Diode  $D_1$  form a current mirror which forces the sum of currents  $I_4$  and  $I_5$  to equal  $I_{ABC}$ :

$$I_4 + I_5 = I_{ABC} \tag{2}$$

where  $I_{ABC}$  is the amplifier bias current applied to the gain pin.

For small differential input voltages the ratio of  $I_4$  and  $I_5$  approaches unity and the Taylor series of the  $\ln$  function can be approximated as:

$$\frac{kT}{q} \ln \frac{I_5}{I_4} \approx \frac{kT}{q} \frac{I_5 - I_4}{I_4} \tag{3}$$

$$I_4 \approx I_5 \approx \frac{I_{ABC}}{2}$$

$$V_{IN} \left[ \frac{I_{ABC}^q}{2kT} \right] = I_5 - I_4 \tag{4}$$

Collector currents  $I_4$  and  $I_5$  are not very useful by themselves and it is necessary to subtract one current from the other. The remaining transistors and diodes form three current mirrors that produce an output current equal to  $I_5$  minus  $I_4$  thus:

$$V_{IN} \left[ \frac{I_{ABC}^q}{2kT} \right] = I_{OUT} \tag{5}$$

The term in brackets is then the transconductance of the amplifier and is proportional to  $I_{ABC}$ .

## Linearizing Diodes

For differential voltages greater than a few millivolts, Equation 3 becomes less valid and the transconductance becomes increasingly nonlinear. Figure 7 demonstrates how the internal diodes can linearize the transfer function of the amplifier. For convenience assume the diodes are biased with current sources and the input signal is in the form of current  $I_S$ . Since the sum of  $I_4$  and  $I_5$  is  $I_{ABC}$  and the difference is  $I_{OUT}$ , currents  $I_4$  and  $I_5$  can be written as follows:

$$I_4 = \frac{I_{ABC}}{2} - \frac{I_{OUT}}{2}, I_5 = \frac{I_{ABC}}{2} + \frac{I_{OUT}}{2} \quad (6)$$

Since the diodes and the input transistors have identical geometries and are subject to similar voltages and temperatures, the following is true:

$$\frac{kT}{q} \ln \frac{I_D + I_S}{I_D - I_S} = \frac{kT}{q} \ln \frac{I_{ABC} + I_{OUT}}{I_{ABC} - I_{OUT}}$$

$$\therefore I_{OUT} = I_S \left( \frac{2I_{ABC}}{I_D} \right) \text{ for } |I_S| < \frac{I_D}{2} \quad (7)$$

Notice that in deriving Equation 7 no approximations have been made and there are no temperature-dependent terms. The limitations are that the signal current not exceed  $I_D/2$  and that the diodes be biased with currents. In practice, replacing the current sources with resistors will generate insignificant errors.

## Applications Voltage Controlled Amplifiers

Figure 8 shows how the linearizing diodes can be used in a voltage-controlled amplifier. To understand the input biasing, it is best to consider the 13 k $\Omega$  resistor as a current source and use a Thevenin equivalent circuit as shown in Figure 9. This circuit is similar to Figure 7 and operates the same. The potentiometer in Figure 8 is adjusted to minimize the effects of the control signal at the output.

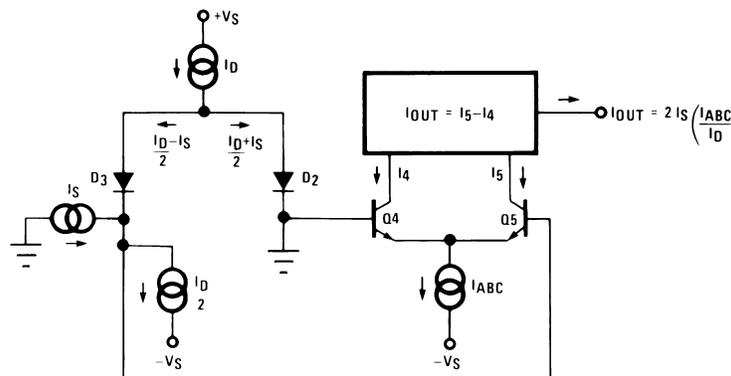


Figure 7. Linearizing Diodes

For optimum signal-to-noise performance,  $I_{ABC}$  should be as large as possible as shown by the Output Voltage vs. Amplifier Bias Current graph. Larger amplitudes of input signal also improve the S/N ratio. The linearizing diodes help here by allowing larger input signals for the same output distortion as shown by the Distortion vs. Differential Input Voltage graph. S/N may be optimized by adjusting the magnitude of the input signal via  $R_{IN}$  (Figure 8) until the output distortion is below some desired level. The output voltage swing can then be set at any level by selecting  $R_L$ .

Although the noise contribution of the linearizing diodes is negligible relative to the contribution of the amplifier's internal transistors,  $I_D$  should be as large as possible. This minimizes the dynamic junction resistance of the diodes ( $r_e$ ) and maximizes their linearizing action when balanced against  $R_{IN}$ . A value of 1 mA is recommended for  $I_D$  unless the specific application demands otherwise.

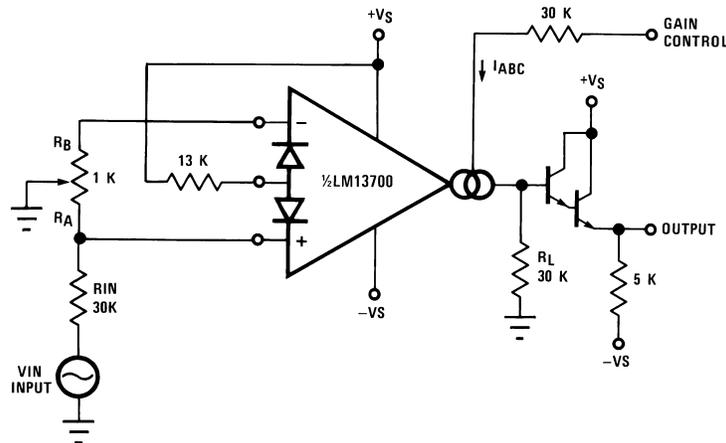


Figure 8. Voltage Controlled Amplifier

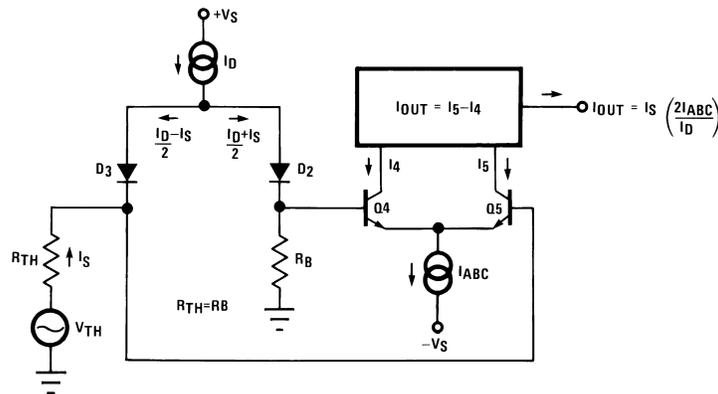


Figure 9. Equivalent VCA Input Circuit

### Stereo Volume Control

The circuit of Figure 10 uses the excellent matching of the two LM13700 amplifiers to provide a Stereo Volume Control with a typical channel-to-channel gain tracking of 0.3 dB.  $R_P$  is provided to minimize the output offset voltage and may be replaced with two 510Ω resistors in AC-coupled applications. For the component values given, amplifier gain is derived for Figure 8 as being:

$$\frac{V_O}{V_{IN}} = 940 \times I_{ABC} \quad (8)$$

If  $V_C$  is derived from a second signal source then the circuit becomes an amplitude modulator or two-quadrant multiplier as shown in Figure 11, where:

$$I_O = \frac{-2I_S}{I_D} (I_{ABC}) = \frac{-2I_S}{I_D} \frac{V_{IN2}}{R_C} - \frac{2I_S}{I_D} \frac{(V^- + 1.4V)}{R_C} \quad (9)$$

The constant term in the above equation may be cancelled by feeding  $I_S \times I_D R_C / 2(V^- + 1.4V)$  into  $I_O$ . The circuit of Figure 12 adds  $R_M$  to provide this current, resulting in a four-quadrant multiplier where  $R_C$  is trimmed such that  $V_O = 0V$  for  $V_{IN2} = 0V$ .  $R_M$  also serves as the load resistor for  $I_O$ .

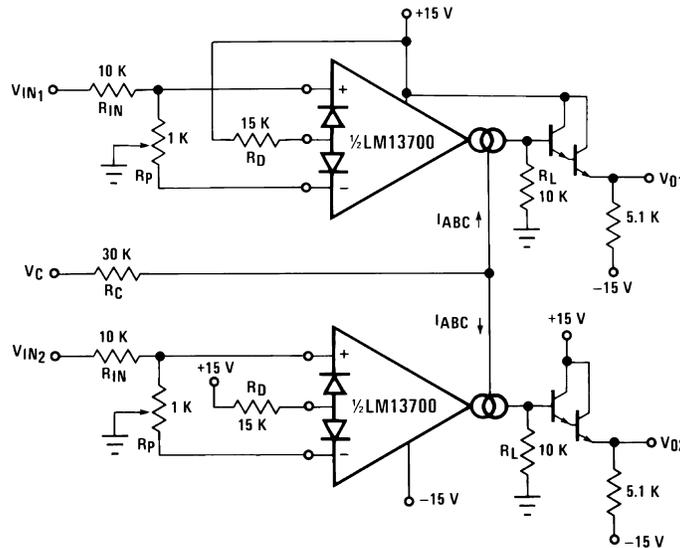


Figure 10. Stereo Volume Control

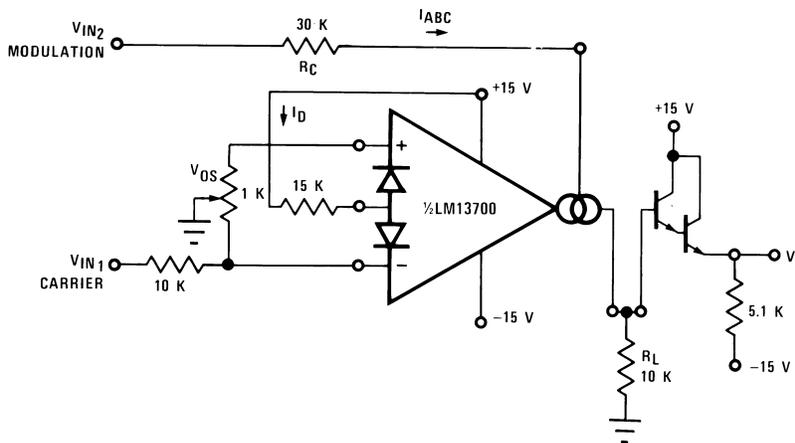


Figure 11. Amplitude Modulator

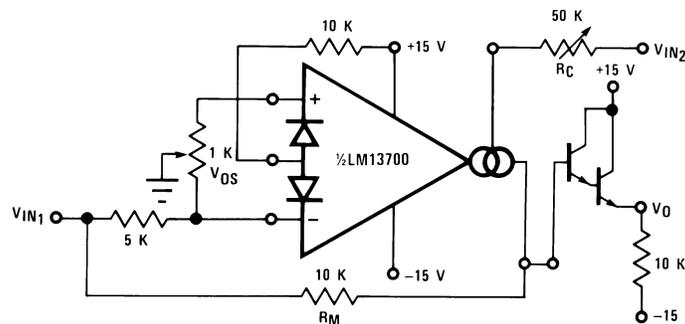


Figure 12. Four-Quadrant Multiplier

Noting that the gain of the LM13700 amplifier of Figure 9 may be controlled by varying the linearizing diode current  $I_D$  as well as by varying  $I_{ABC}$ , Figure 13 shows an AGC Amplifier using this approach. As  $V_O$  reaches a high enough amplitude ( $3V_{BE}$ ) to turn on the Darlington transistors and the linearizing diodes, the increase in  $I_D$  reduces the amplifier gain so as to hold  $V_O$  at that level.

### Voltage Controlled Resistors

An Operational Transconductance Amplifier (OTA) may be used to implement a Voltage Controlled Resistor as shown in Figure 14. A signal voltage applied at  $R_X$  generates a  $V_{IN}$  to the LM13700 which is then multiplied by the  $g_m$  of the amplifier to produce an output current, thus:

$$R_X = \frac{R + R_A}{g_m R_A} \quad (10)$$

where  $g_m \approx 19.2I_{ABC}$  at 25°C. Note that the attenuation of  $V_O$  by  $R$  and  $R_A$  is necessary to maintain  $V_{IN}$  within the linear range of the LM13700 input.

Figure 15 shows a similar VCR where the linearizing diodes are added, essentially improving the noise performance of the resistor. A floating VCR is shown in Figure 16, where each “end” of the “resistor” may be at any voltage within the output voltage range of the LM13700.

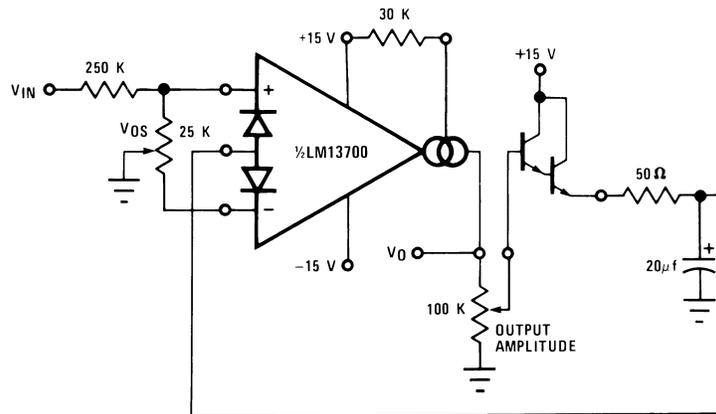


Figure 13. AGC Amplifier

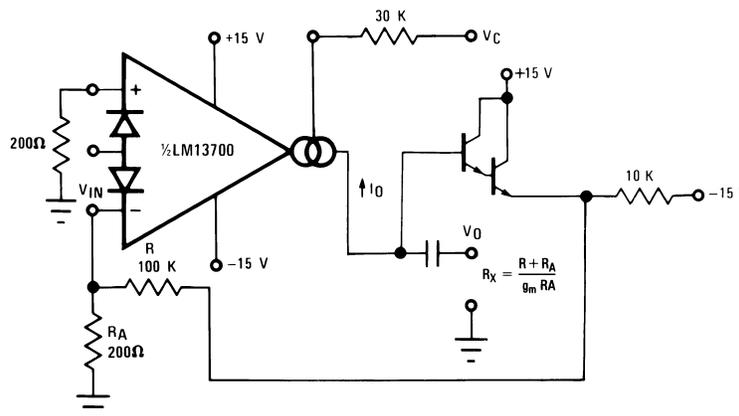


Figure 14. Voltage Controlled Resistor, Single-Ended

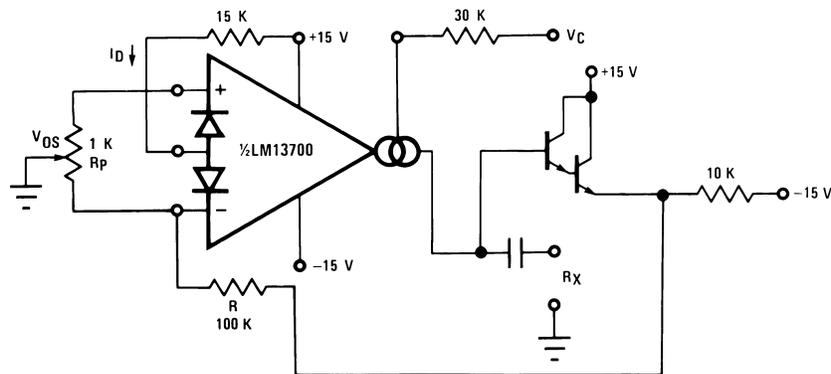


Figure 15. Voltage Controlled Resistor with Linearizing Diodes

### Voltage Controlled Filters

OTA's are extremely useful for implementing voltage controlled filters, with the LM13700 having the advantage that the required buffers are included on the I.C. The VC Lo-Pass Filter of Figure 17 performs as a unity-gain buffer amplifier at frequencies below cut-off, with the cut-off frequency being the point at which  $X_C/g_m$  equals the closed-loop gain of  $(R/R_A)$ . At frequencies above cut-off the circuit provides a single RC roll-off (6 dB per octave) of the input signal amplitude with a  $-3$  dB point defined by the given equation, where  $g_m$  is again  $19.2 \times I_{ABC}$  at room temperature. Figure 18 shows a VC High-Pass Filter which operates in much the same manner, providing a single RC roll-off below the defined cut-off frequency.

Additional amplifiers may be used to implement higher order filters as demonstrated by the two-pole Butterworth Lo-Pass Filter of Figure 19 and the state variable filter of Figure 20. Due to the excellent  $g_m$  tracking of the two amplifiers, these filters perform well over several decades of frequency.

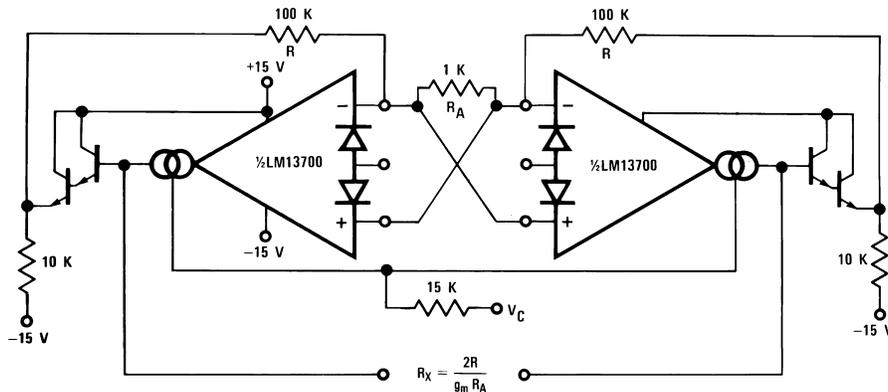


Figure 16. Floating Voltage Controlled Resistor

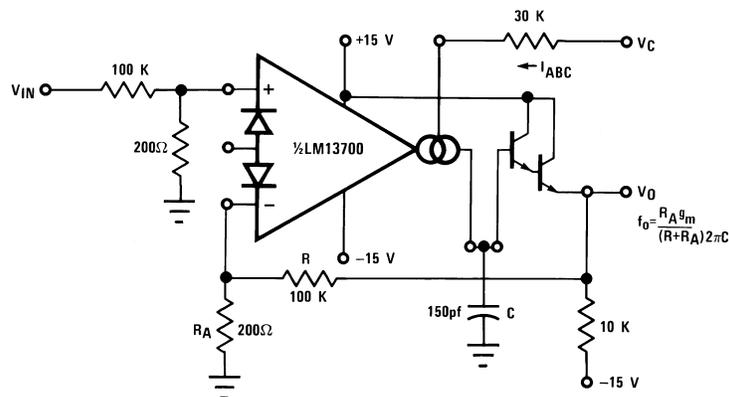
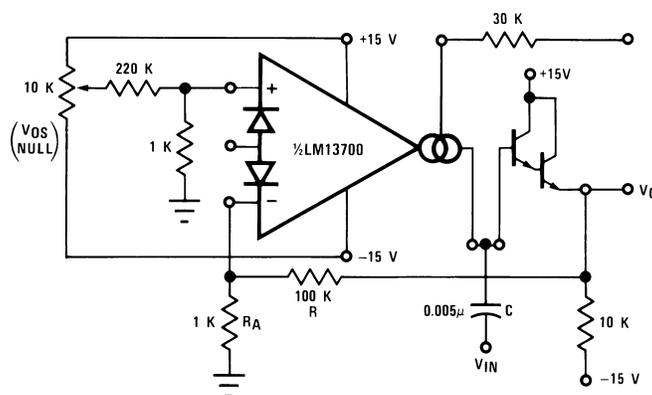
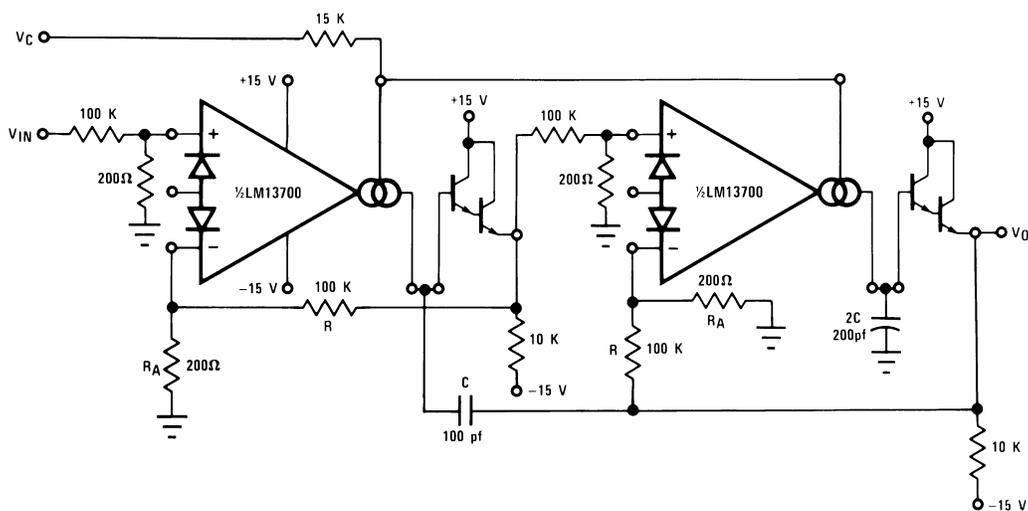


Figure 17. Voltage Controlled Low-Pass Filter



$$f_0 = \frac{R_A g_m}{(R + R_A) 2\pi C}$$

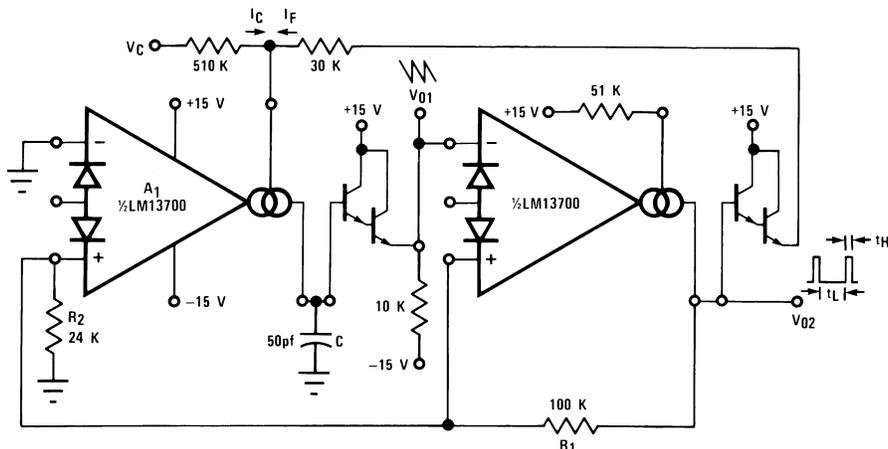
Figure 18. Voltage Controlled Hi-Pass Filter



$$f_0 = \frac{R_A g_m}{(R + R_A) 2\pi C}$$

Figure 19. Voltage Controlled 2-Pole Butterworth Lo-Pass Filter





$$V_{PK} = \frac{(V^+ \pm 0.8V) R_2}{R_1 + R_2}$$

$$t_H \approx \frac{2V_{PK}C}{I_F}$$

$$t_L = \frac{2V_{PK}C}{I_C}$$

$$f_0 \approx \frac{I_C}{2V_{PK}C} \text{ for } I_C \ll I_F$$

Figure 22. Ramp/Pulse VCO

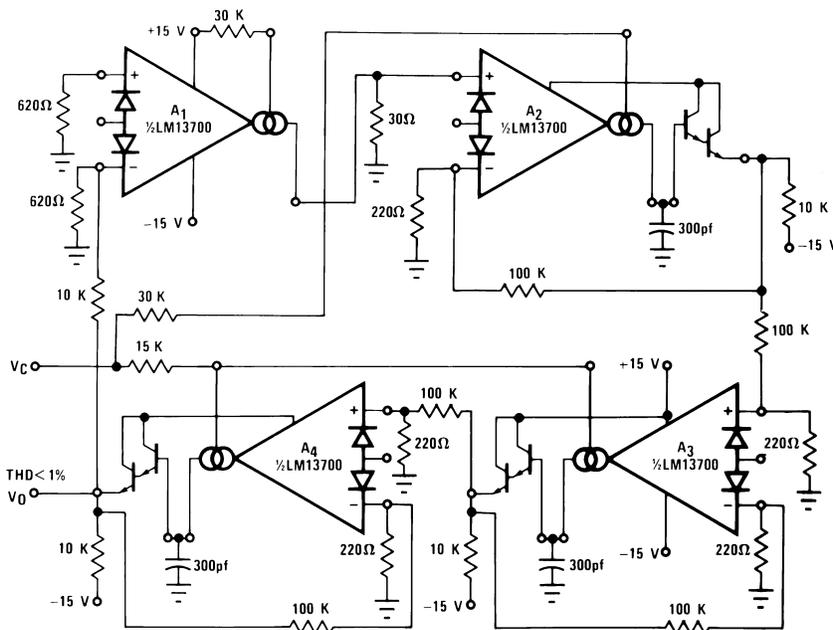
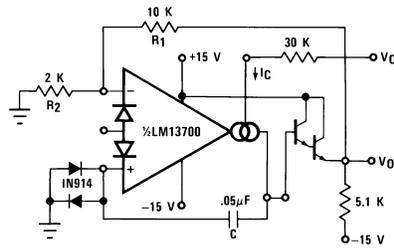


Figure 23. Sinusoidal VCO

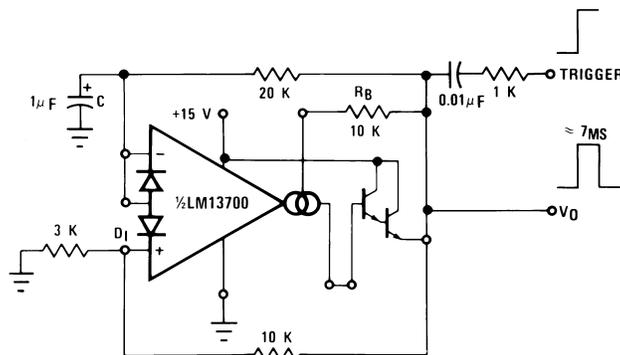
Figure 24 shows how to build a VCO using one amplifier when the other amplifier is needed for another function.



**Figure 24. Single Amplifier VCO**

## Additional Applications

Figure 25 presents an interesting one-shot which draws no power supply current until it is triggered. A positive-going trigger pulse of at least 2V amplitude turns on the amplifier through  $R_B$  and pulls the non-inverting input high. The amplifier regenerates and latches its output high until capacitor C charges to the voltage level on the non-inverting input. The output then switches low, turning off the amplifier and discharging the capacitor. The capacitor discharge rate is speeded up by shorting the diode bias pin to the inverting input so that an additional discharge current flows through  $D_1$  when the amplifier output switches low. A special feature of this timer is that the other amplifier, when biased from  $V_O$ , can perform another function and draw zero stand-by power as well.



**Figure 25. Zero Stand-By Power Timer**

The operation of the multiplexer of Figure 26 is very straightforward. When A1 is turned on it holds  $V_O$  equal to  $V_{IN1}$  and when A2 is supplied with bias current then it controls  $V_O$ .  $C_C$  and  $R_C$  serve to stabilize the unity-gain configuration of amplifiers A1 and A2. The maximum clock rate is limited to about 200 kHz by the LM13700 slew rate into 150 pF when the  $(V_{IN1} - V_{IN2})$  differential is at its maximum allowable value of 5V.

The Phase-Locked Loop of Figure 27 uses the four-quadrant multiplier of Figure 12 and the VCO of Figure 24 to produce a PLL with a  $\pm 5\%$  hold-in range and an input sensitivity of about 300 mV.

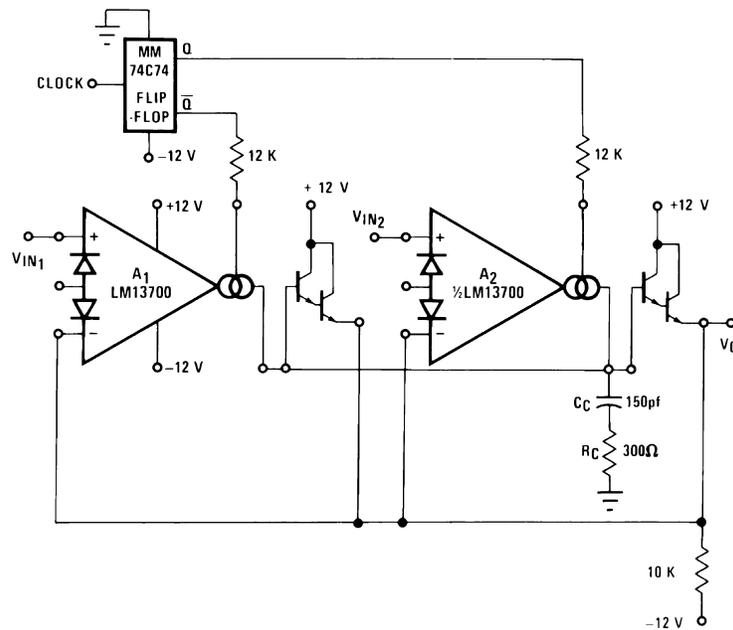


Figure 26. Multiplexer

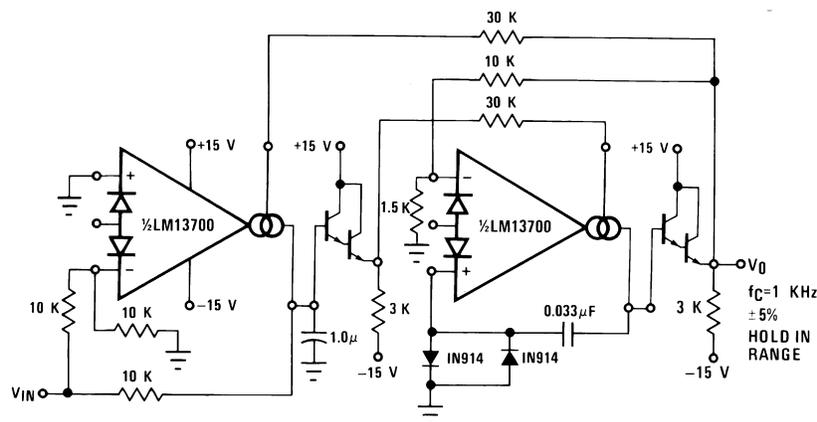


Figure 27. Phase Lock Loop

The Schmitt Trigger of [Figure 28](#) uses the amplifier output current into R to set the hysteresis of the comparator; thus  $V_H = 2 \times R \times I_B$ . Varying  $I_B$  will produce a Schmitt Trigger with variable hysteresis.

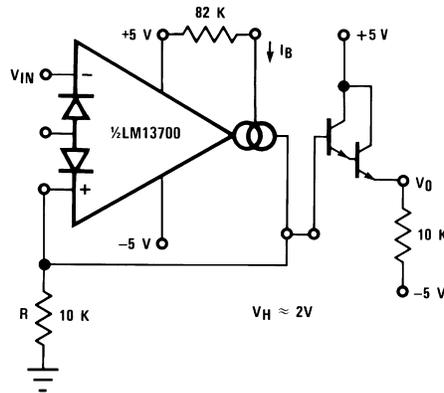


Figure 28. Schmitt Trigger

Figure 29 shows a Tachometer or Frequency-to-Voltage converter. Whenever A1 is toggled by a positive-going input, an amount of charge equal to  $(V_H - V_L) C_f$  is sourced into  $C_f$  and  $R_f$ . This once per cycle charge is then balanced by the current of  $V_O/R_f$ . The maximum  $F_{IN}$  is limited by the amount of time required to charge  $C_f$  from  $V_L$  to  $V_H$  with a current of  $I_B$ , where  $V_L$  and  $V_H$  represent the maximum low and maximum high output voltage swing of the LM13700. D1 is added to provide a discharge path for  $C_f$  when A1 switches low.

The Peak Detector of Figure 30 uses A2 to turn on A1 whenever  $V_{IN}$  becomes more positive than  $V_O$ . A1 then charges storage capacitor C to hold  $V_O$  equal to  $V_{IN}$  PK. Pulling the output of A2 low through D1 serves to turn off A1 so that  $V_O$  remains constant.

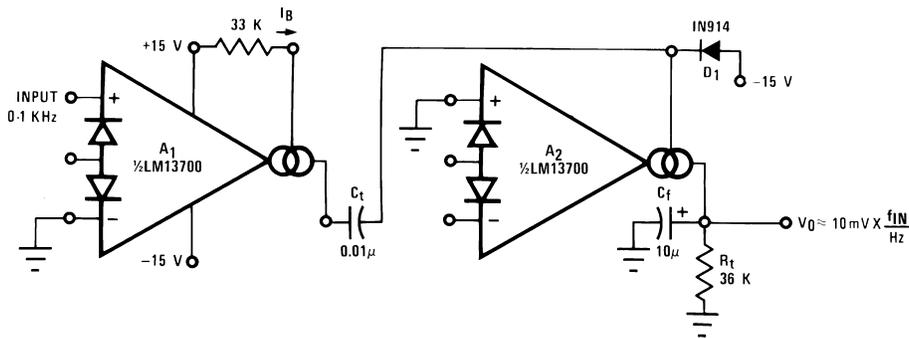


Figure 29. Tachometer

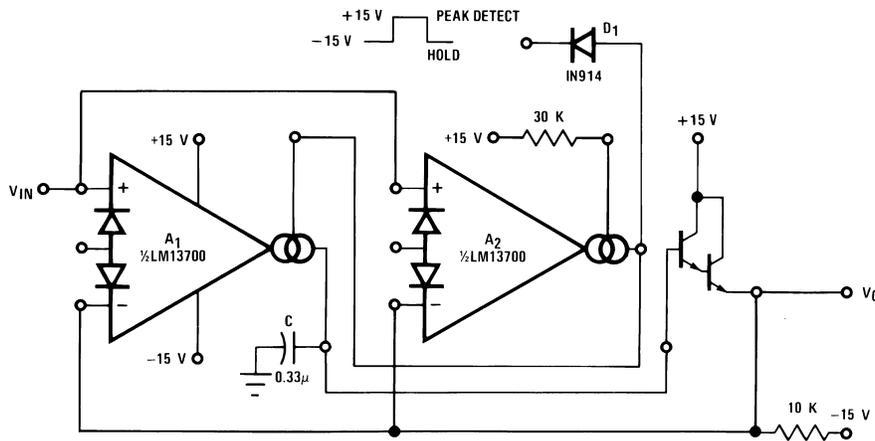


Figure 30. Peak Detector and Hold Circuit

The Ramp-and-Hold of Figure 32 sources  $I_B$  into capacitor C whenever the input to A1 is brought high, giving a ramp-rate of about 1V/ms for the component values shown.

The true-RMS converter of Figure 33 is essentially an automatic gain control amplifier which adjusts its gain such that the AC power at the output of amplifier A1 is constant. The output power of amplifier A1 is monitored by squaring amplifier A2 and the average compared to a reference voltage with amplifier A3. The output of A3 provides bias current to the diodes of A1 to attenuate the input signal. Because the output power of A1 is held constant, the RMS value is constant and the attenuation is directly proportional to the RMS value of the input voltage. The attenuation is also proportional to the diode bias current. Amplifier A4 adjusts the ratio of currents through the diodes to be equal and therefore the voltage at the output of A4 is proportional to the RMS value of the input voltage. The calibration potentiometer is set such that  $V_O$  reads directly in RMS volts.

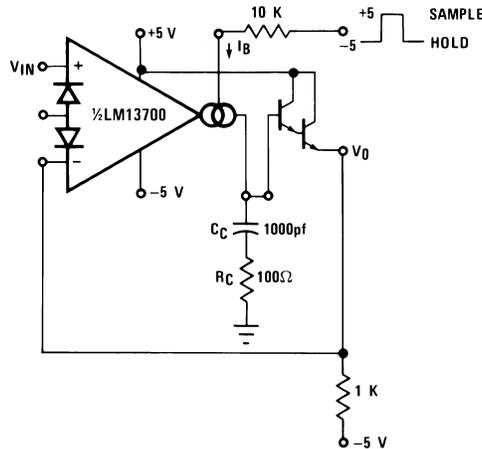


Figure 31. Sample-Hold Circuit

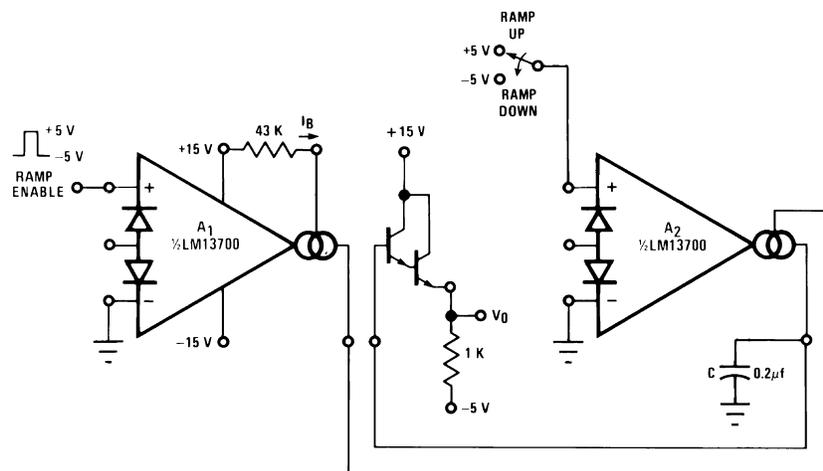
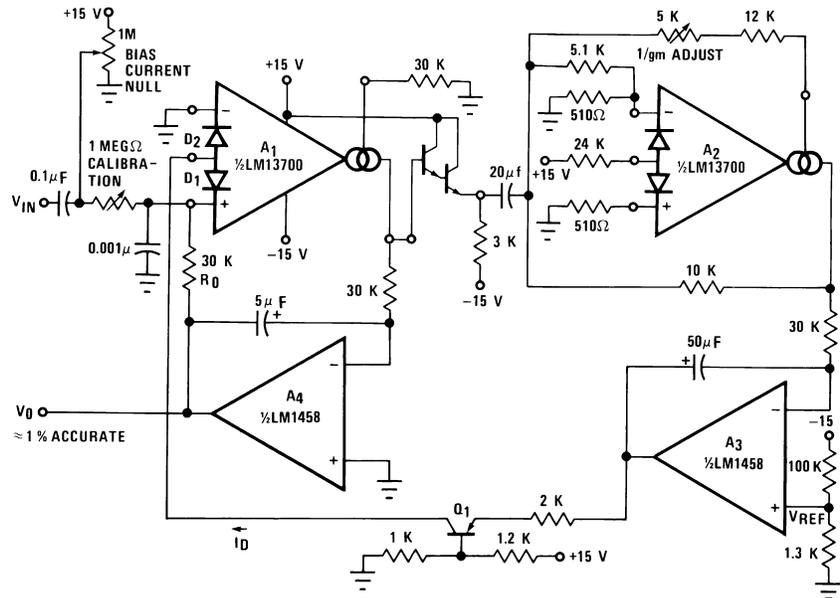


Figure 32. Ramp and Hold



**Figure 33. True RMS Converter**

The circuit of [Figure 34](#) is a voltage reference of variable Temperature Coefficient. The 100 kΩ potentiometer adjusts the output voltage which has a positive TC above 1.2V, zero TC at about 1.2V, and negative TC below 1.2V. This is accomplished by balancing the TC of the A2 transfer function against the complementary TC of D1.

The wide dynamic range of the LM13700 allows easy control of the output pulse width in the Pulse Width Modulator of [Figure 35](#).

For generating  $I_{ABC}$  over a range of 4 to 6 decades of current, the system of [Figure 36](#) provides a logarithmic current out for a linear voltage in.

Since the closed-loop configuration ensures that the input to A2 is held equal to 0V, the output current of A1 is equal to  $I_3 = -V_C/R_C$ .

The differential voltage between Q1 and Q2 is attenuated by the R1,R2 network so that A1 may be assumed to be operating within its linear range. From [Equation 5](#), the input voltage to A1 is:

$$V_{IN1} = \frac{-2kT I_3}{q I_2} = \frac{-2kT V_C}{q I_2 R_C} \quad (11)$$

The voltage on the base of Q1 is then

$$V_{B1} = \frac{(R_1 + R_2) V_{IN1}}{R_1} \quad (12)$$

The ratio of the Q1 and Q2 collector currents is defined by:

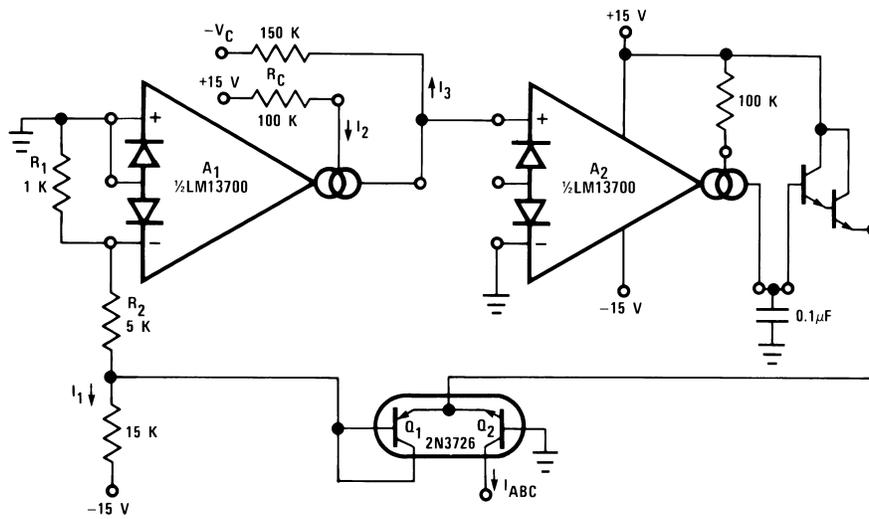
$$V_{B1} = \frac{kT}{q} \ln \frac{I_{C2}}{I_{C1}} \approx \frac{kT}{q} \ln \frac{I_{ABC}}{I_1} \quad (13)$$

Combining and solving for  $I_{ABC}$  yields:

$$I_{ABC} = I_1 \exp \frac{2(R_1 + R_2) V_C}{R_1 I_2 R_C} \quad (14)$$

This logarithmic current can be used to bias the circuit of [Figure 10](#) to provide temperature independent stereo attenuation characteristic.





$$I_{ABC} = I_1 \exp \frac{-CI_3}{I_2}$$

Figure 36. Logarithmic Current Source

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Samples (Requires Login)
LM13700M	ACTIVE	SOIC	D	16	48	TBD	CU SNPB	Level-1-235C-UNLIM	
LM13700M/NOPB	ACTIVE	SOIC	D	16	48	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	
LM13700MX	ACTIVE	SOIC	D	16	2500	TBD	CU SNPB	Level-1-235C-UNLIM	
LM13700MX/NOPB	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	
LM13700N	ACTIVE	PDIP	NFG	16	25	TBD	Call TI	Level-1-NA-UNLIM	
LM13700N/NOPB	ACTIVE	PDIP	NFG	16	25	Pb-Free (RoHS)	CU SN	Level-1-NA-UNLIM	

<sup>(1)</sup> The marketing status values are defined as follows:

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**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

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**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

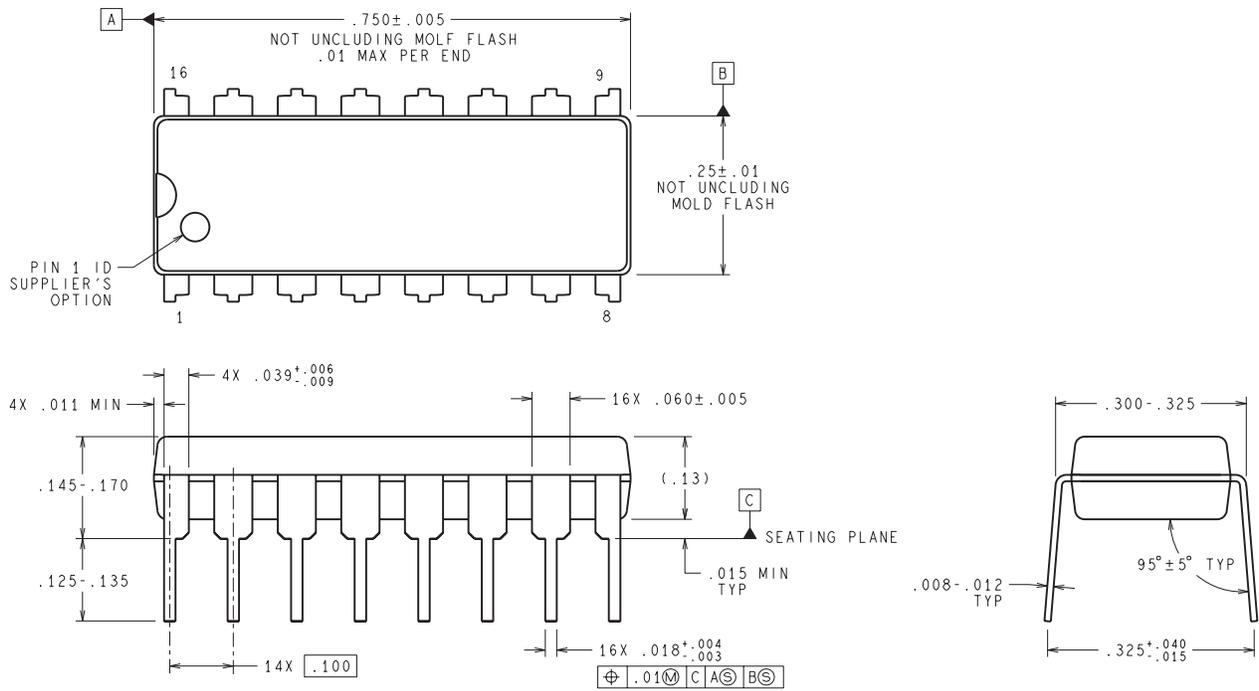
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM13700MX	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1
LM13700MX/NOPB	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM13700MX	SOIC	D	16	2500	349.0	337.0	45.0
LM13700MX/NOPB	SOIC	D	16	2500	349.0	337.0	45.0

NFG0016E

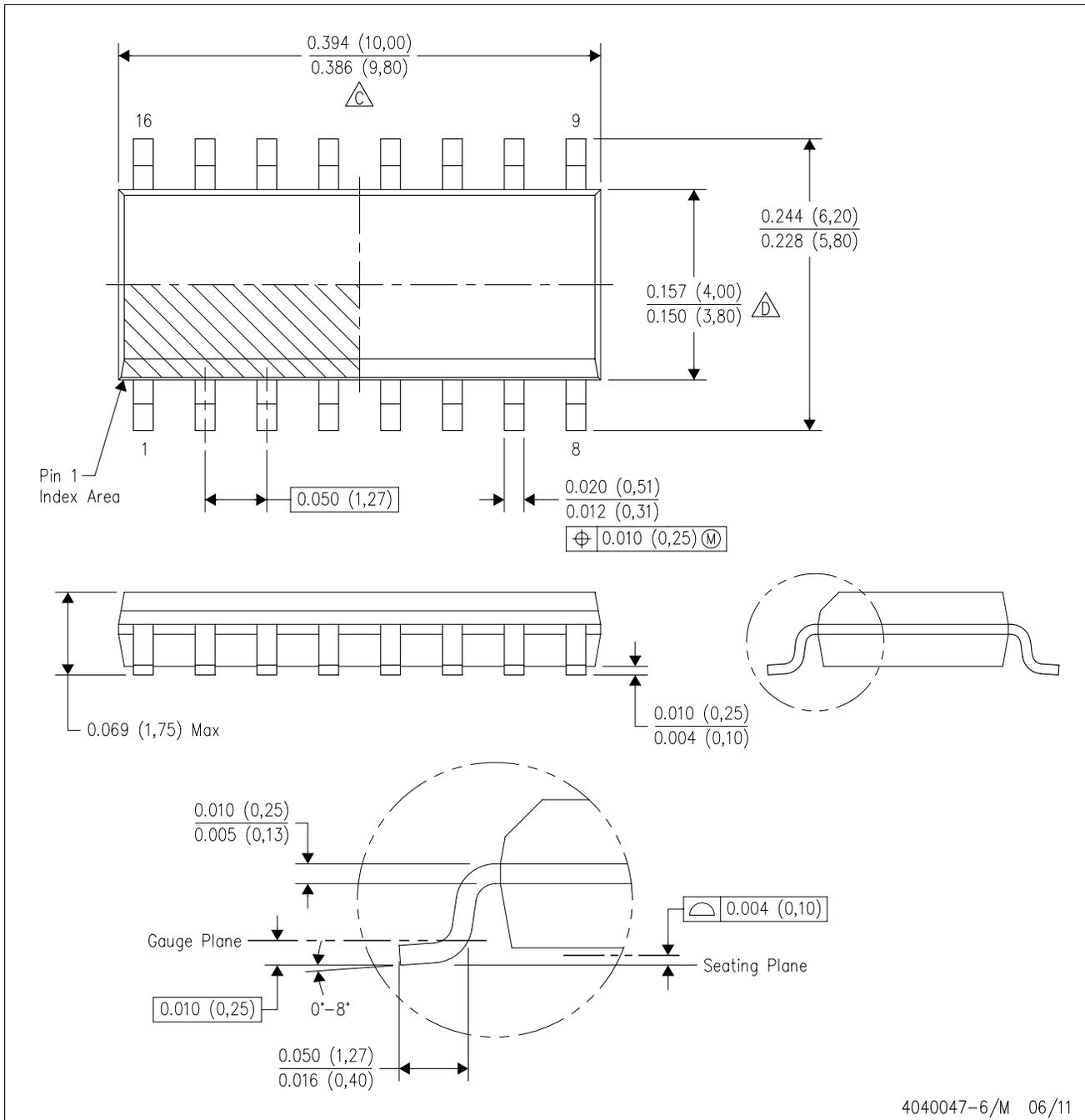


**DIMENSIONS ARE IN INCHES**  
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N16E (Rev G)

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4040047-6/M 06/11

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  - B. This drawing is subject to change without notice.
  -  C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
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